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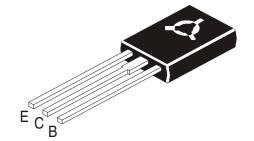


TÜV MANAGEMENT SERVICE

An ISO/TS16949 and ISO 9001 Certified Company

NPN EPITAXIAL SILICON POWER TRANSISTOR





TO126 Plastic Package

For use in High Voltage General Purpose Applications

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Emitter Voltage	V_{CEO}	300	V
Collector Base Voltage	V_{CBO}	300	V
Emitter Base Voltage	V_{EBO}	3.0	V
Collector Current Continuous	I _C	500	mA
Power Dissipation @ T _a =25 ^o C	P_D	1.25	W
Derate above 25°C		10	mW/ºC
Power Dissipation @ T _c =25°C	P_{D}	20	W
Derate above 25°C		0.16	W/ºC
Operating And Storage Junction Temperature Range	T _j , T _{stg}	- 65 to +150	ōC

THERMAL CHARACTERISTICS

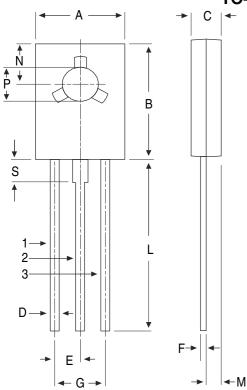
Junction to Ambient in free air	R _{th (j-a)}	100	ºC/W
Junction to Case	R _{th (j-c)}	6.25	ºC/W

ELECTRICAL CHARACTERISTICS (T_c=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Collector Emitter Sustaining Voltage	*V _{CEO (sus)}	$I_C=1$ mA, $I_B=0$	300		V
Collector Cut Off Current	Сво	V_{CB} =300 $V_{,}I_{E}$ =0		100	μΑ
Emitter Cut Off Current	I _{EBO}	$V_{EB}=3V$, $I_{C}=0$		100	μΑ
DC Current Gain	h _{FE}	I _C =50mA, V _{CE} =10V	30	240	

TO126 Plastic Package

TO-126 (SOT-32) Plastic Package



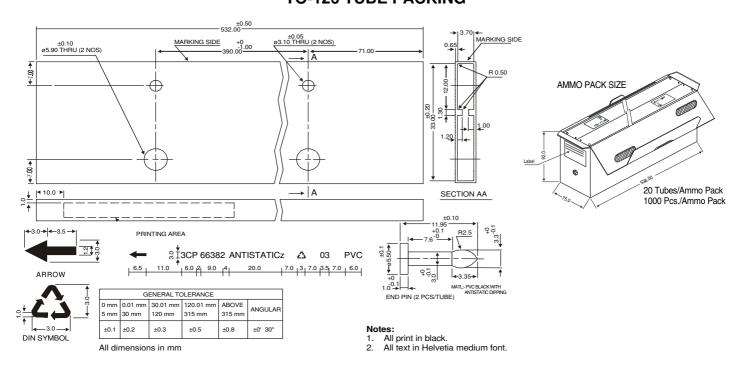
DIM	MIN	MAX		
Α	7.4	7.8		
В	10.5	10.8		
С	2.4	2.7		
D	0.7	0.9		
Е	2.25 TYP.			
F	0.49	0.75		
G	4.5 TYP.			
L	15.7 TYP.			
М	1.27 TYP.			
N	3.75 TYP.			
Р	3.0	3.2		
S	2.5 TYP.			

1 2 3 Die Configuration

- Pin Configuration
- 1. Emitter
- 2. Collector
- 3. Base

TO-126 TUBE PACKING

All dimensions in mm.



Packing Details

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/ Oty	Size	Qty	Size	Qty	Gr Wt
TO-126 Bulk	500 pcs/polybag	340 gm/500 pcs	3" x 7.5" x 7.5"	2K	17" x 15" x 13.5"	32K	31 kgs
TO-126 Tube	50 pcs/tube	73 gm/50 pcs	3" x 3.7" x 21.5"	1K	19" x 19" x 19"	10K	15 kgs

Notes MJE340

TO126
Plastic Package

Disclaimer

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